INTEGRATED CIRCUIT TOSHIBA TECHNICAL DATA

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT TA2058F

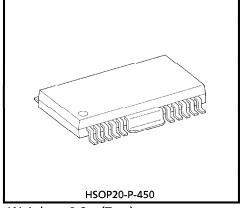
SILICON MONOLITHIC

POWER DRIVER IC FOR CD PLAYER

TA2058F is a power driver IC developed for CD players. This IC have built-in 4 channel BTL power amplifiers which drives focus-coil and tracking coil for 3-beam pick-up head, disc motor and feed motor.

FEATURES

- 4 channel BTL linear divers
- Few external parts
- Fixed voltage gain
 - : Gv = 15dB (Typ.)
- High output power
 - : $V_{OM}1 = 5V_{p-p}$ (Typ.) $V_{CC} = 5V$, $R_L = 50HM$
 - : $V_{OM}2 = 6V_{p-p}$ (Typ.) $V_{CC} = 6V$, $R_L = 50HM$
- Thermal shut down protector
- Input reference voltage short protector
- Small Package
 - : Power-flat package 1mm pitch 20pins
- Operation Supply Voltage Range
 - : $V_{CC(opr)} = 4.0 \sim 10.0 \text{V} \text{ (Ta} = 25 ^{\circ}\text{C)}$



Weight: 0.8g (Typ.)

(1)

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
 These TOSHIBA products are intended for use in general commercial applications (office equipment, communication equipment, measuring

These TOSHIBA products are intended for use in general commercial applications (office equipment, communication equipment, measuring equipment, domestic appliances, etc.), please make sure that you consult with us before you use these TOSHIBA products in equipment which requires extraordinarily high quality and/or reliability, and in equipment which may involve life threatening or critical application, including but not limited to such uses as atomic energy control, airplane or spaceship instrumentation, traffic signals, medical instrumentation, combustion control, all types of safety devices, etc. TOSHIBA cannot accept and hereby disclaims liability for any damage which may occur in case the TOSHIBA products are used in such equipment or applications without prior consultation with TOSHIBA.

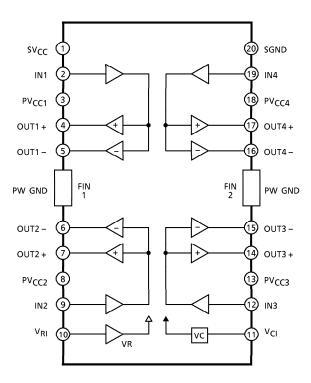
TA2058F

TOSHIBA

TECHNICAL DATA

INTEGRATED CIRCUIT

BLOCK DIAGRAM



TA2058F – 2	
1996 – 4 – 22	

TECHNICAL DATA

TERMINAL EXPLANATION

	EXPLAINA		1
TERMINAL No.	3 TIVIBUL	FUNCTION	EQUIVALENT CIRCUIT
1	sv_{CC}	Supply terminal of small signal	
2	IN1	Input for CH1 ■ Not biased inside.	SGND SGND
3	PVCC1	Supply terminal of output stage for CH1 • Supply terminal of output stage are not connected to other channel terminal.	SV _{CC} PV _{CC}
4	OUT1+	Non-inverted output for CH1	OUT
5	OUT1 –	Inverted output for CH1	<u> </u>
FIN1	PGND	Power GND • Connected to FIN2 and substrate.	PGND
6	OUT2 –	Inverted output for CH2	Same as CH1
7	OUT2+	Non-inverted output for CH2	1
8	PV _{CC2}	Supply terminal of output stage for CH2	1
9	IN2	Input for CH2	1
10	V _{RI}	 Input reference voltage Under condition of V_{R1}≤ 1.8V, internal bias circuit is shut off. 	30kΩ 39kΩ
11	V _{CI}	Output reference voltage ■ V _{OUT} = V _{CI} = (V _{CC} – VF) / 2	ONDS ONDS
12	IN3	Input for CH3	Same as CH1
13	PV _{CC3}	Supply terminal of output stage for CH3	_
14	OUT3+	Non-inverted output for CH3	
15	OUT3 –	Inverted output for CH3	
FIN2	PGND	Power GND	Connected to FIN1
16	OUT4 –	Inverted output for CH4	Same as CH1
17	OUT4+	Non-inverted output for CH4	1
18	PV _{CC4}	Supply terminal of output stage for CH4	
19	IN4	Input for CH4	
20	SGND	Small signal GND	

TA2058F – 3
1996 – 4 – 22
TOSHIBA CORPORATION

TECHNICAL DATA

TA2058F

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V _{CC}	14	V
Power Dissipation	P _D (Note 1)	2 (Note 2)	W
Operating Temperature	T _{opr}	- 30∼85	°C
Storage Temperature	T _{stg}	- 55∼150	°C

(Note 1): Mounted on 50mm x 50mm x 1.6mm size board with copper area 60% over.

(Note 2) : Derated above $Ta = 25^{\circ}C$, in the proportion of $62.5 \text{mW}/^{\circ}C$.

ELECTRICAL CHARACTERISTICS

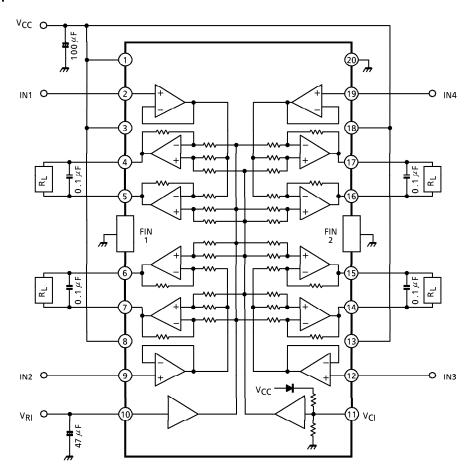
(Unless otherwise specified, V_{CC} = 5V, R_L = 5 Ω , Rg = 620 Ω , V_{RI} = 2.1V, f = 1kHz, Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Operating Voltage	Vcc	-		4.0	_	10.0	V
Quiescent Current	lccQ	—	Vin = 0, R _L = OPEN	20	35	60	mA
Input Offset Current	IN	—	VIN = 2.1V	_	250	800	nA
V _{RI} Terminal Offset Current	l ₁₀	_	V _{RI} = 2.1V	_	35	120	μΑ
	Vo osi	-	$V_{CC} = 5V$, $Rg = 0\Omega$	- 30	_	30	
Output Offset Voltage	Vo os2	_	$V_{CC} = 8V$, $Rg = 0\Omega$	- 50	_	50	mV
	VO OS3	_	$V_{CC} = 12V$, $Rg = 0\Omega$	- 100	_	100	
Reference Output Voltage	VOUT	_		_	2.1	_	V
Maximum Output Valtage	V _{OM} 1	_	V _{CC} = 5V	4.0	5.0	_	\ /
Maximum Output Voltage	V _{OM} 2	_	V _{CC} = 6V	5.0	6.0	_	V _{p-p}
Voltage Gain	Gv	_	Vin = 100mV _{rms}	14.5	15.5	16.5	dB
Frequency Response	fc	—	Vin = 100mV _{rms}	_	100	_	kHz
Total Harmonic Distortion	THD	<u> </u>	Vin = 100mV _{rms}	_	- 50	_	dB
Slew Rate	S.R.	_	Vout = 2V _{p-p}	_	1.0	_	V / μ s
Cross Talk	C.T.	_	Vout = 1V _{rms}	_	- 60	_	dB
Ripple Rejection Ratio	R.R.		frip = 100Hz, Vrip = 100mV _{rms}	_	- 60	_	dB
Thermal Shut Down Temperature	T _{TSD}		Chip temperature		150		°C
V _{RI} ~GND Short Protection Voltage	VRI OFF	_		1.4	1.6	1.8	٧

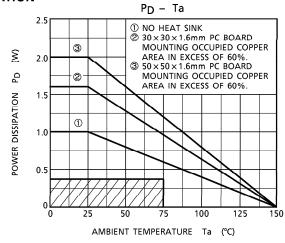
TA2058F – 4	
1996 – 4 – 22	

TECHNICAL DATA

TEST CIRCUIT



HSOP 20 POWER DISSIPATION

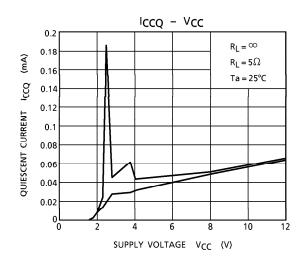


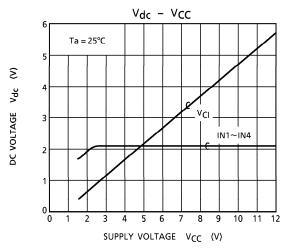
(Note) In case of normal use, power dissipation of IC only is oblique line portion.

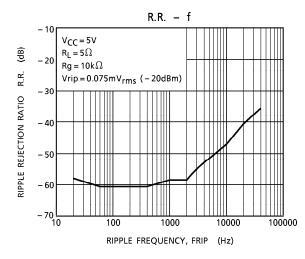
TA2058F – 5
1996 – 4 – 22
TOSHIBA CORPORATION

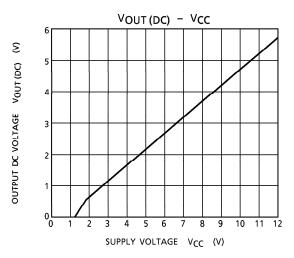
TECHNICAL DATA

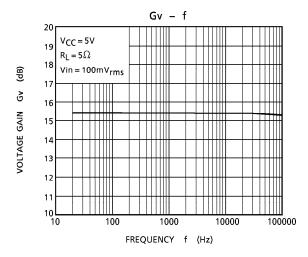
TA2058F







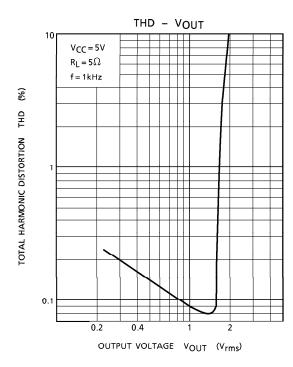


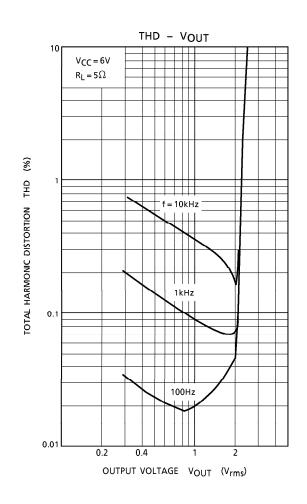


TA2058F – 6
1996 – 4 – 22
TOSHIBA CORPORATION

TA2058F

TECHNICAL DATA

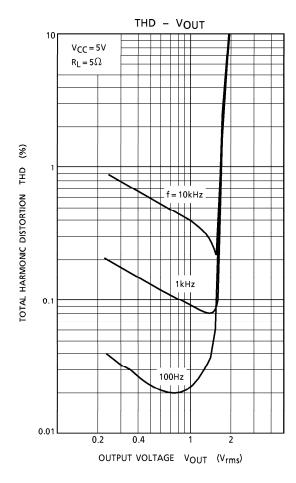


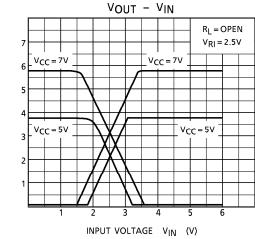


TA2058F – 7
1996 – 4 – 22

TECHNICAL DATA

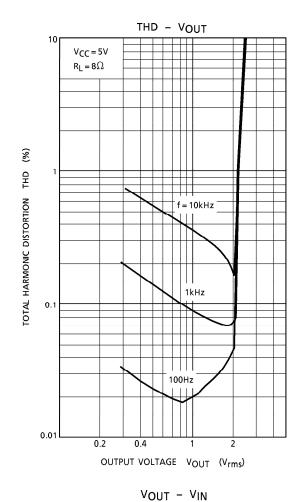
TA2058F

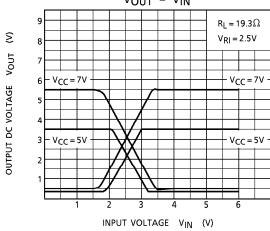




S

OUTPUT DC VOLTAGE VOUT

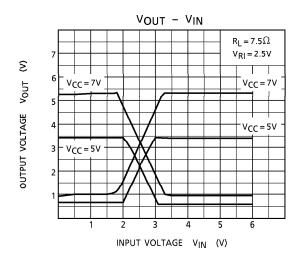


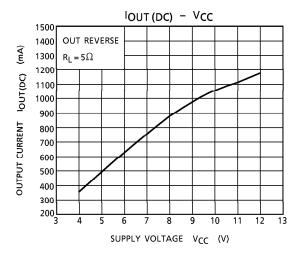


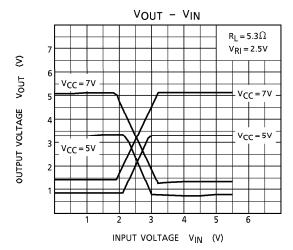
TA2058F – 8
1996 – 4 – 22

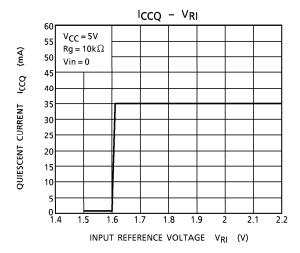
TECHNICAL DATA

TA2058F









TA2058F – 9
1996 – 4 – 22

TECHNICAL DATA

PRECAUTION USE

• Input Stage

 Input stages are consisted of differential circuit of NPN Tr, and have built-in IB compensation circuit.

Built-in Driver

- Each channel driver consists of BTL configuration linear amplifier.
- Voltage gain is fixed: Gy = 15.5dB (Typ.)
- Voltage loss for output stage is 2V_{BE} + V_{CE} (sat) for positive cycle, V_{CE} (sat) for negative cycle, because of no-bootstrap circuit. So, output DC voltage is designed as less than 1/2V_{CC}.

V_{RI} Terminal

- V_{RI} is reference voltage terminal for input signal.
- If reference voltage from servo IC drop less than 1.8V, protection circuit operates and shut off bias circuit inside. This operation is to prevent load from moving undesirably in case of V_{RI} drop for accident or some reason.

V_{CI} Terminal

- Output DC voltage is determined by circuit of this terminal inside as ;
 - $V_{CI} = V_{OUT} (DC) = (V_{CC} V_F) / 2$
- Output signal dynamic range is depend on V_{CC}. On the other hand, input signal dynamic range
 is determined by V_RI as mentioned and voltage gain is fixed inside. So, maximum output voltage
 does not increase as V_{CC} increases.
- Because of BTL configuration, Ripple Rejection Ratio does not improve not much when capacitor is connected to V_{Cl} terminal to GND.

GND

- Large signal GND is for output stage and small signal GND is for stages from input circuit to pre-output stage.
- These GND pins are not connected inside.
- Phin① and Phin② are connected to Bedflame, and it is connected to substrate.
- It is advised that you make a Printed Board layout of small signal GND and large signal GND should be isolated each other.

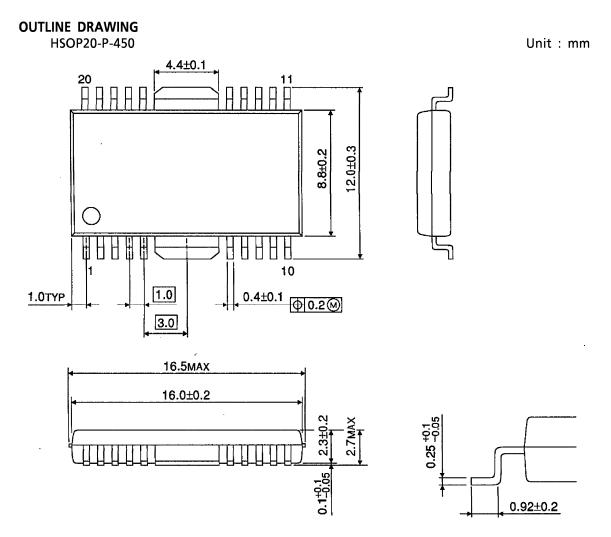
Oscillation preventive capacitor

- We recommend to use the capacitor of $0.1\mu\text{F}$, between each output terminals. But perform the temperature test to check the oscillation allowance, since the oscillation allowance is varied according to the causes described below.
- 1) Supply voltage
- 2) Ambient temperature
- 3) Load impedance
- 4) Capacity value of condenser
- 5) Kind of condenser
- 6) Layout of Printed board
- We recommend to connect Pass-condenser, which is about 10 to 100μ F between V_{RI} terminal and GND.
- V_{CI} terminal is recommend to use "OPEN".

TA2058F – 10
1996 – 4 – 22
TOSHIBA CORROBATION

TECHNICAL DATA

TA2058F



Weight: 0.8g (Typ.)

TA2058F – 11*
1996 – 4 – 22
TOPHIBA CODDODATION